

# 74LVT273

3.3 V octal D-type flip-flop

Rev. 03 — 10 September 2008

Product data sheet

## 1. General description

The 74LVT273 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3 V.

This device has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ( $\overline{MR}$ ) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independent of the clock or data inputs by a LOW voltage level on the  $\overline{MR}$  input. The device is useful for applications where only the true output is required and the CP and  $\overline{MR}$  are common elements.

## 2. Features

- Eight edge-triggered D-type flip-flops
- Buffered common clock and asynchronous master reset
- Input and output interface capability to systems at 5 V supply
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Output capability: +64 mA/-32 mA
- Latch-up protection
  - ◆ JESD78 Class II exceeds 500 mA
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Bus-hold data inputs eliminate the need for external pull-up resistors for unused inputs
- Live insertion/extraction permitted
- Power-up reset
- No bus current loading when output is tied to 5 V bus

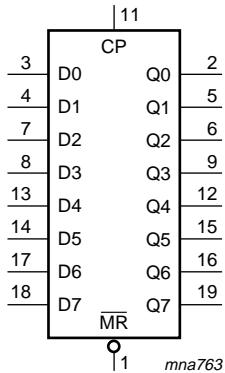


### 3. Ordering information

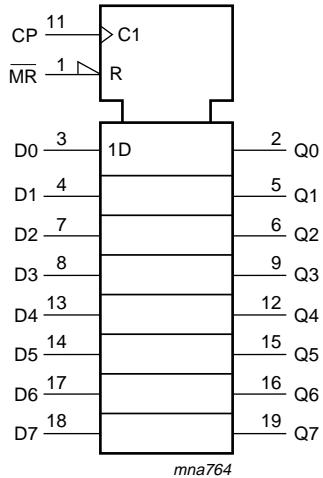
**Table 1. Ordering information**

Type number	Package	Temperature range	Name	Description	Version
74LVT273D	SO20	−40 °C to +125 °C		plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74LVT273DB	SSOP20	−40 °C to +125 °C		plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74LVT273PW	TSSOP20	−40 °C to +125 °C		plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74LVT273BQ	DHVQFN20	−40 °C to +125 °C		plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

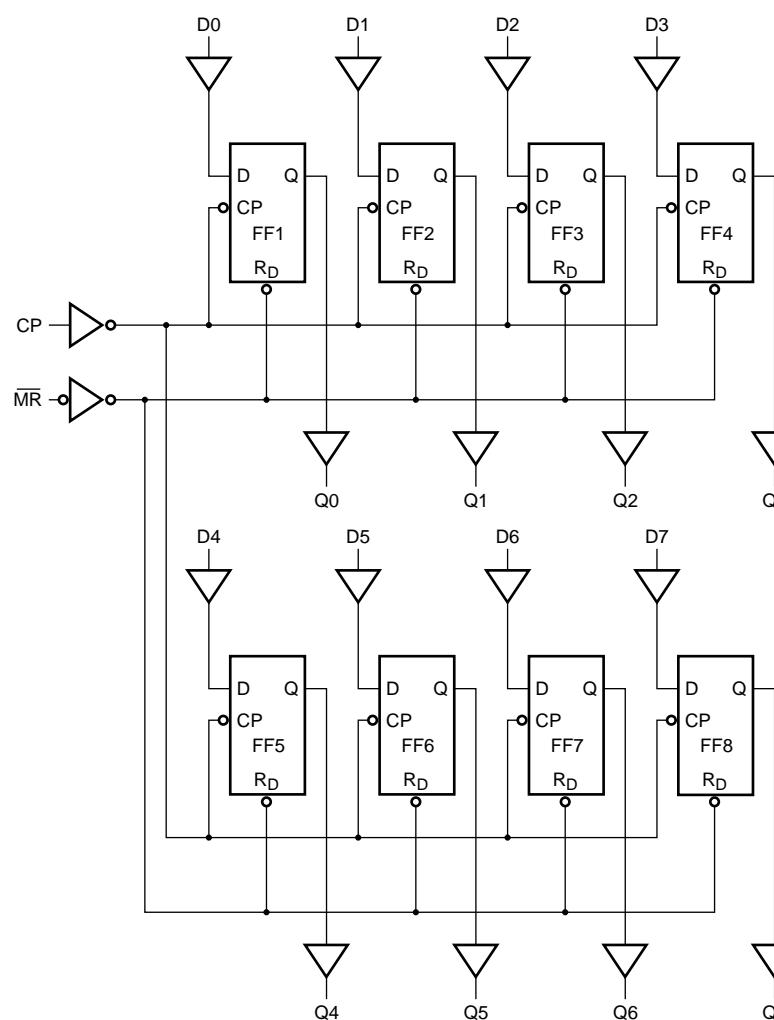
### 4. Functional diagram



**Fig 1. Logic symbol**



**Fig 2. IEC logic symbol**



001aae056

Fig 3. Logic diagram

## 5. Pinning information

### 5.1 Pinning

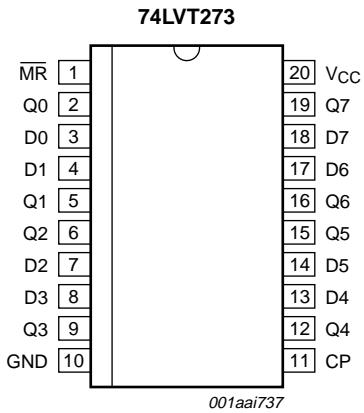
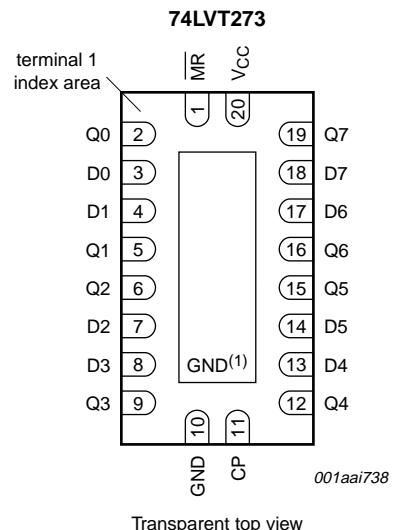


Fig 4. Pin configuration for SO20 and (T)SSOP20



- (1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig 5. Pin configuration for DHVQFN20

### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	1	master reset input (active LOW)
Q0 to Q7	2, 5, 6, 9, 12, 15, 16, 19	data output
D0 to D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
CP	11	clock pulse input (active on rising edge)
V <sub>CC</sub>	20	positive supply voltage

## 6. Functional description

**Table 3. Function selection**

Inputs			Outputs		Operating mode
MR	CP	Dn	Qn		
L	X	X	L		Reset (clear)
H	↑	h	H		Load 1
H	↑	I	L		Load 0
H	L	X	Q0		Retain state

- [1] H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the prior to the LOW-to-HIGH clock transition;  
 L = LOW voltage level; I = LOW voltage level one set-up time prior to the prior to the LOW-to-HIGH clock transition;  
 X = Don't care; ↑ = LOW-to-HIGH clock transition; Q0 = output as it was.

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
V <sub>I</sub>	input voltage		[1] -0.5	+7.0	V
V <sub>O</sub>	output voltage	Output in OFF or HIGH state	[1] -0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
I <sub>O</sub>	output current	output in LOW state	-	128	mA
		output in HIGH state	-64	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		[2] -	150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +85 °C	[3]	500	mW

- [1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.  
 [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.  
 [3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.  
 For SSOP20 and TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.  
 For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CC</sub>	supply voltage		2.7	-	3.6	V
V <sub>I</sub>	input voltage		0	-	5.5	V
I <sub>OH</sub>	HIGH-level output current		-32	-	-	mA



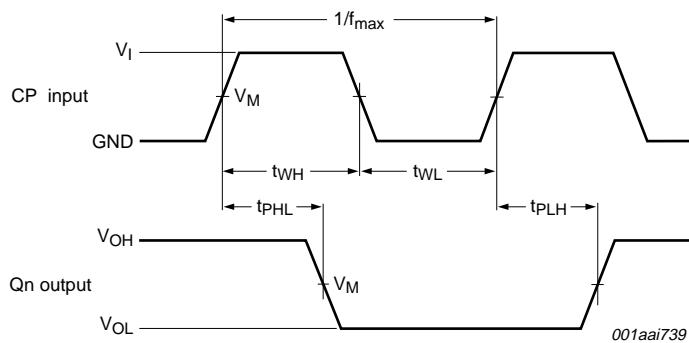


**Table 7. Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 9](#).

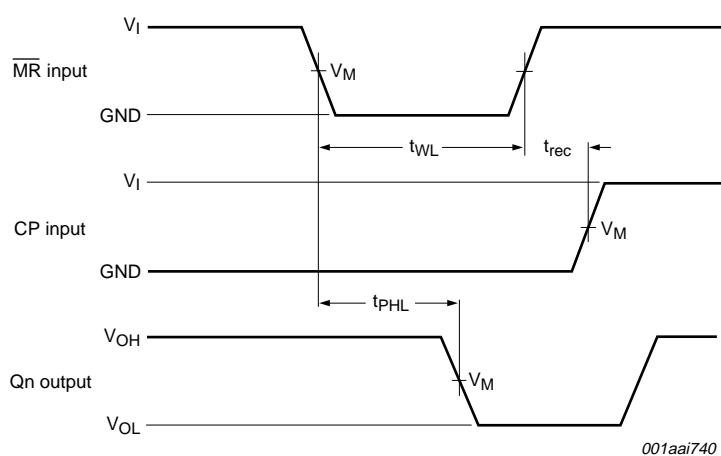
Symbol	Parameter	Conditions	-40 °C to +85 °C			Unit	
			Min	Typ <sup>[1]</sup>	Max		
$t_W$	pulse width	CP input HIGH or LOW; see <a href="#">Figure 6</a> [4]					
			$V_{CC} = 2.7 \text{ V}$	3.3	-	- ns	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	3.3	1.5	- ns	
	MR input LOW; see <a href="#">Figure 7</a>						
			$V_{CC} = 2.7 \text{ V}$	3.3	-	- ns	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	3.3	1.5	- ns	
$t_{rec}$	recovery time	see <a href="#">Figure 7</a>					
			$V_{CC} = 2.7 \text{ V}$	3.2	-	- ns	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	2.7	1.0	- ns	
$f_{max}$	maximum frequency	CP input; see <a href="#">Figure 7</a>	150	-	-	MHz	

[1] Typical values are measured at  $T_{amb} = 25 \text{ }^{\circ}\text{C}$  and  $V_{CC} = 3.3 \text{ V}$ [2]  $t_{su}$  is the same as  $t_{su(L)}$  and  $t_{su(H)}$ [3]  $t_h$  is the same as  $t_{h(L)}$  and  $t_{h(H)}$ [4]  $t_W$  is the same as  $t_{WL}$  and  $t_{WH}$ 

## 11. Waveforms

see [Table 8](#) for measurement points. $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.**Fig 6. CP Input to Qn output propagation delays and clock pulse width and maximum frequency****Table 8. Measurement points**

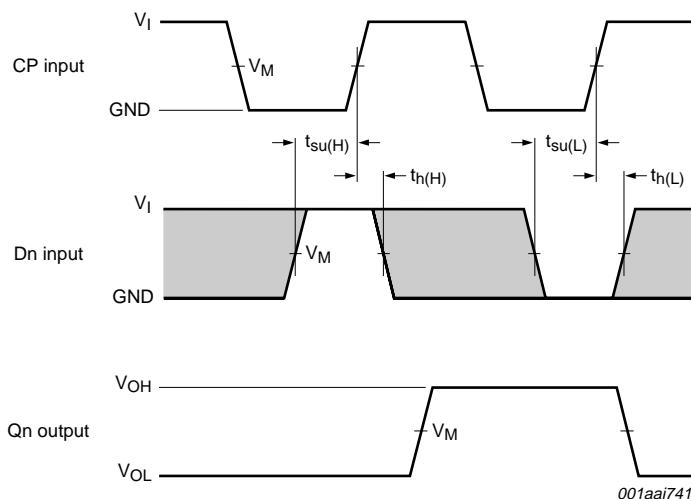
Input		Output
$V_I$	$V_M$	$V_M$
2.7 V	1.5 V	1.5 V



see [Table 8](#) for measurement points.

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 7.  $\overline{MR}$  pulse width,  $\overline{MR}$  to CP recovery time and  $\overline{MR}$  to Qn delay**

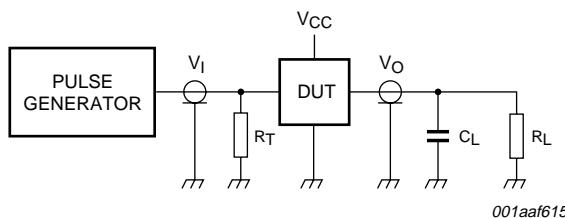
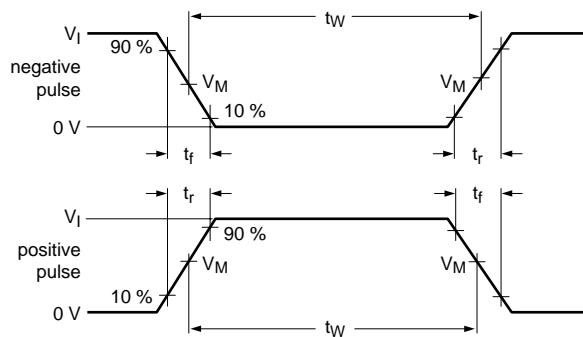


see [Table 8](#) for measurement points.

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

The shaded areas indicate when the input is permitted to change for predictable output performance.

**Fig 8. Data set-up and hold times**



Test data is given in given in [Table 9](#).

Definitions for test circuit:

$R_L$  = Load resistance;

$C_L$  = Load capacitance including jig and probe capacitance;

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

**Fig 9. Load circuitry for switching times**

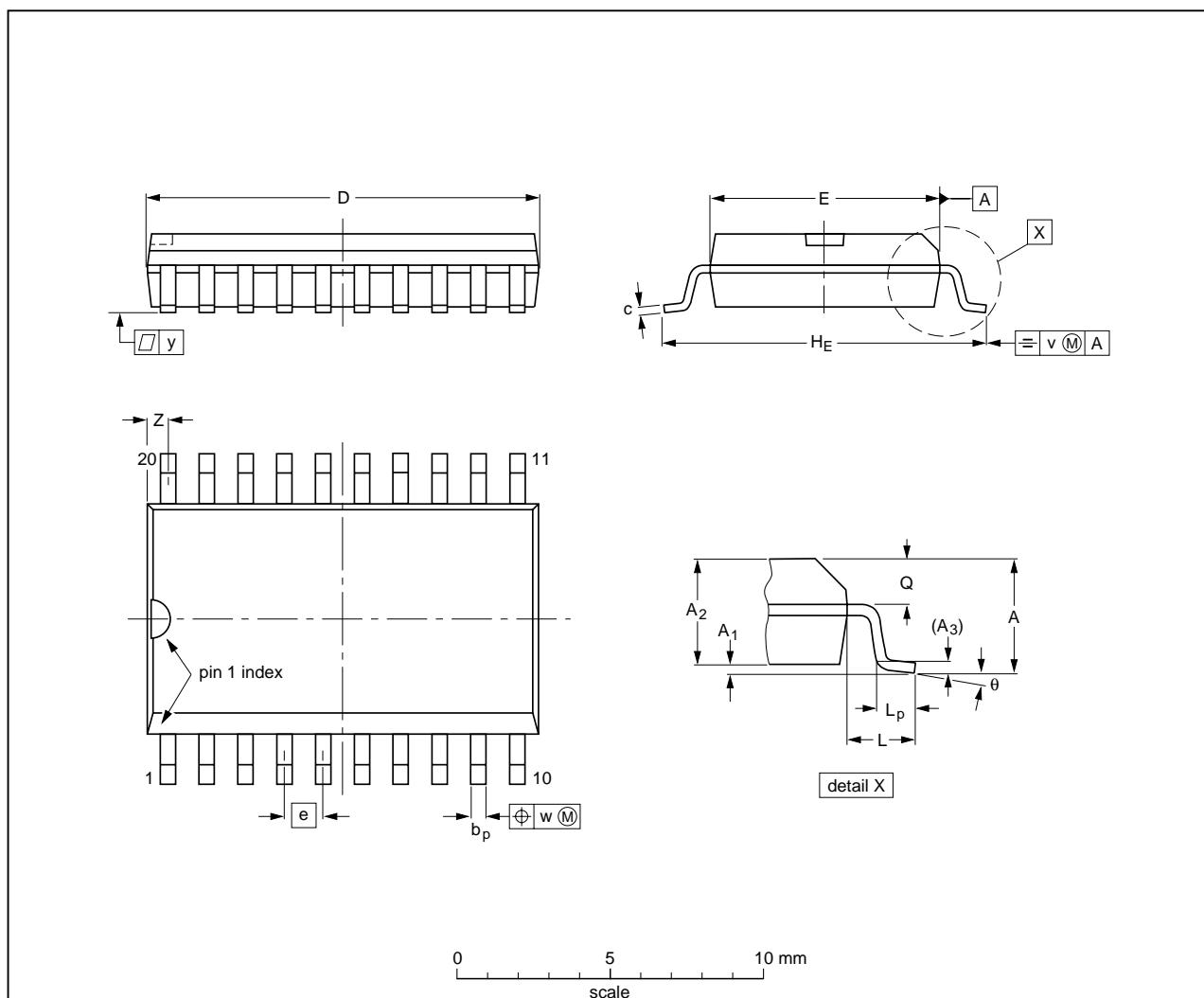
**Table 9. Test data**

Input				Load	
$V_I$	Repetition rate	$t_W$	$t_r, t_f$	$R_L$	$C_L$
2.7 V	$\leq 10$ MHz	500 ns	$\leq 2.5$ ns	500 $\Omega$	50 pF

## 12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	z <sup>(1)</sup>	θ
mm	2.65 0.1	0.3 2.25	2.45 0.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8° 0°
inches	0.1 0.004	0.012 0.089	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0° 0°

### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT163-1	075E04	MS-013			-99-12-27 03-02-19

Fig 10. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

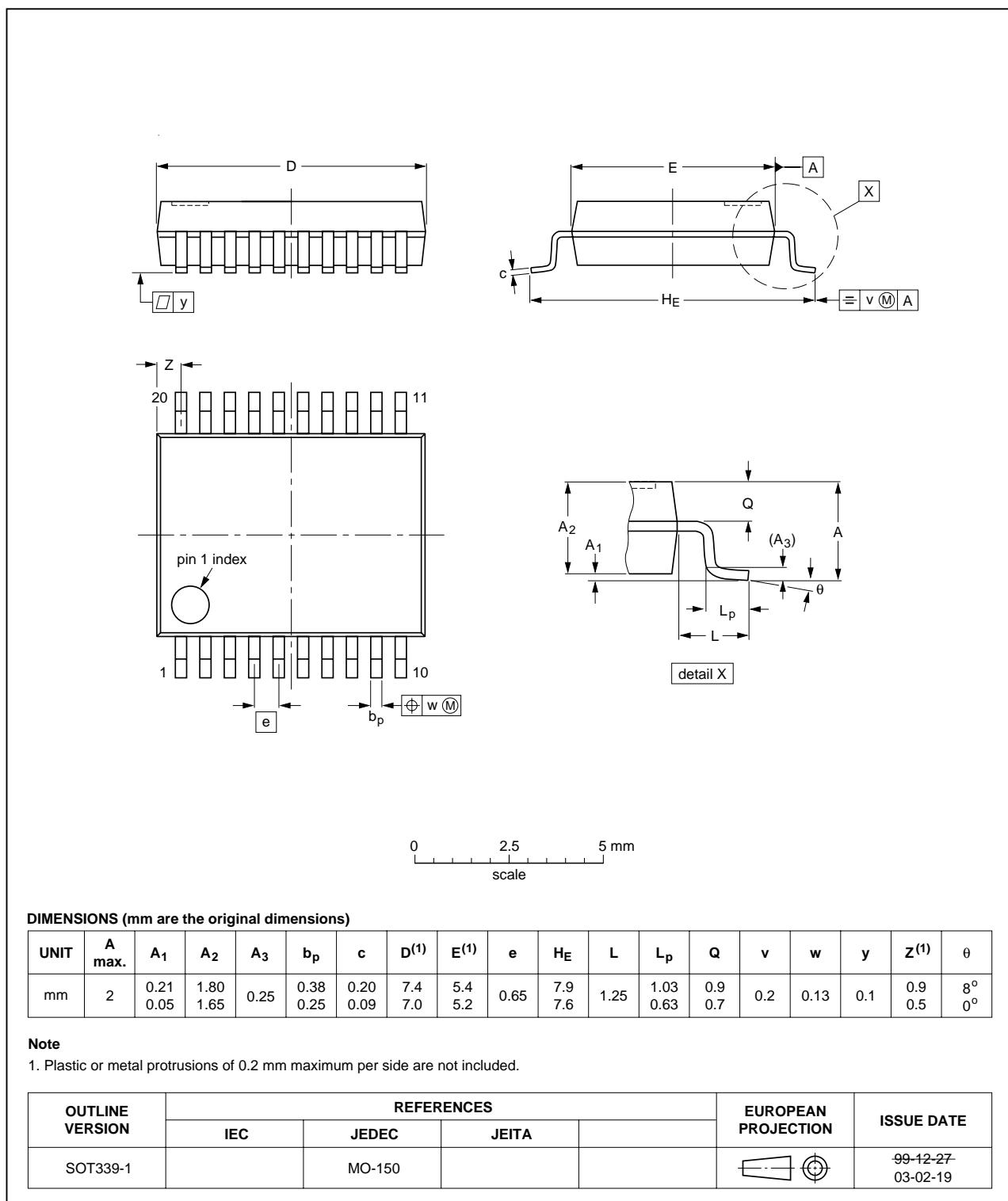


Fig 11. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

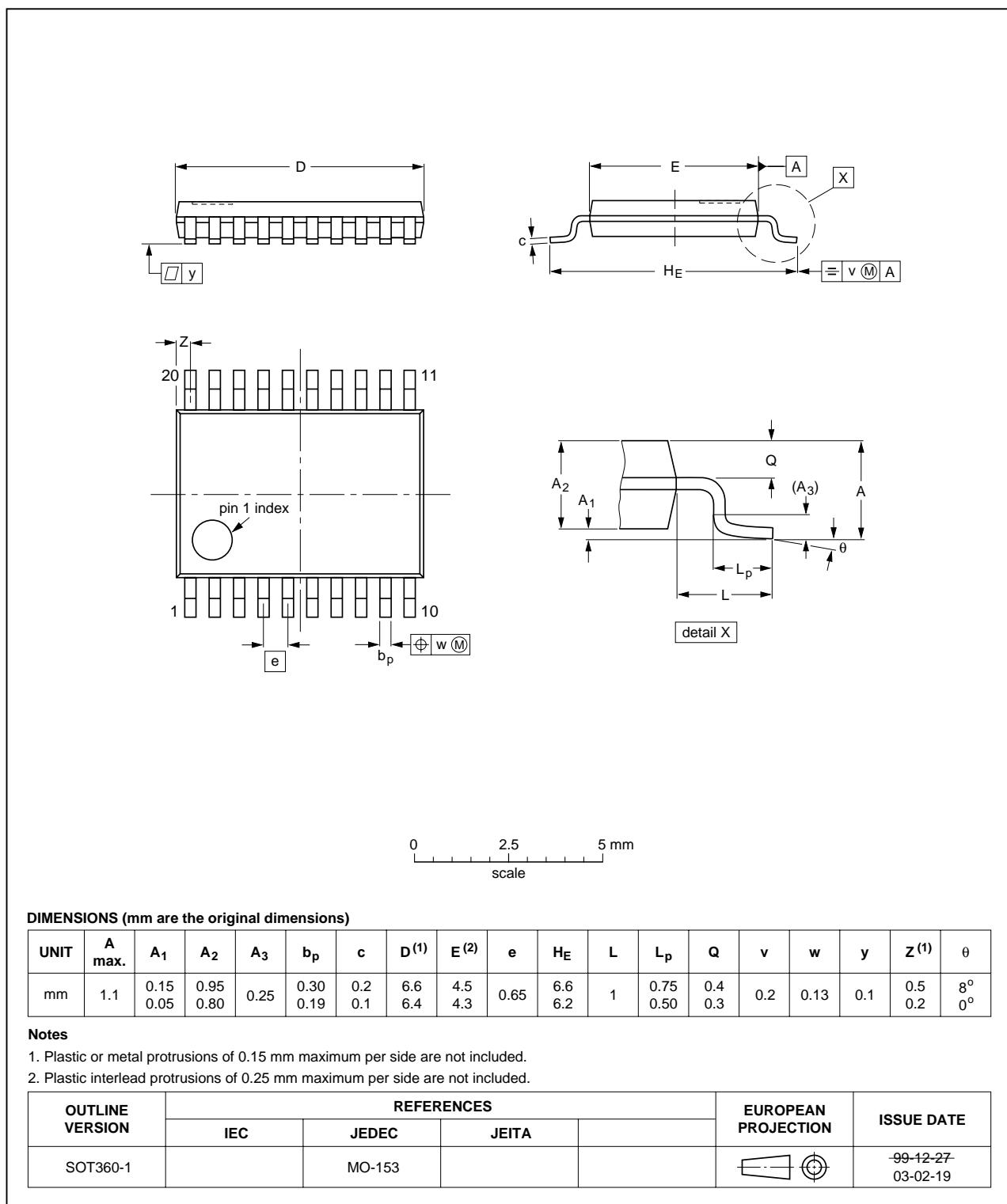


Fig 12. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;  
20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1

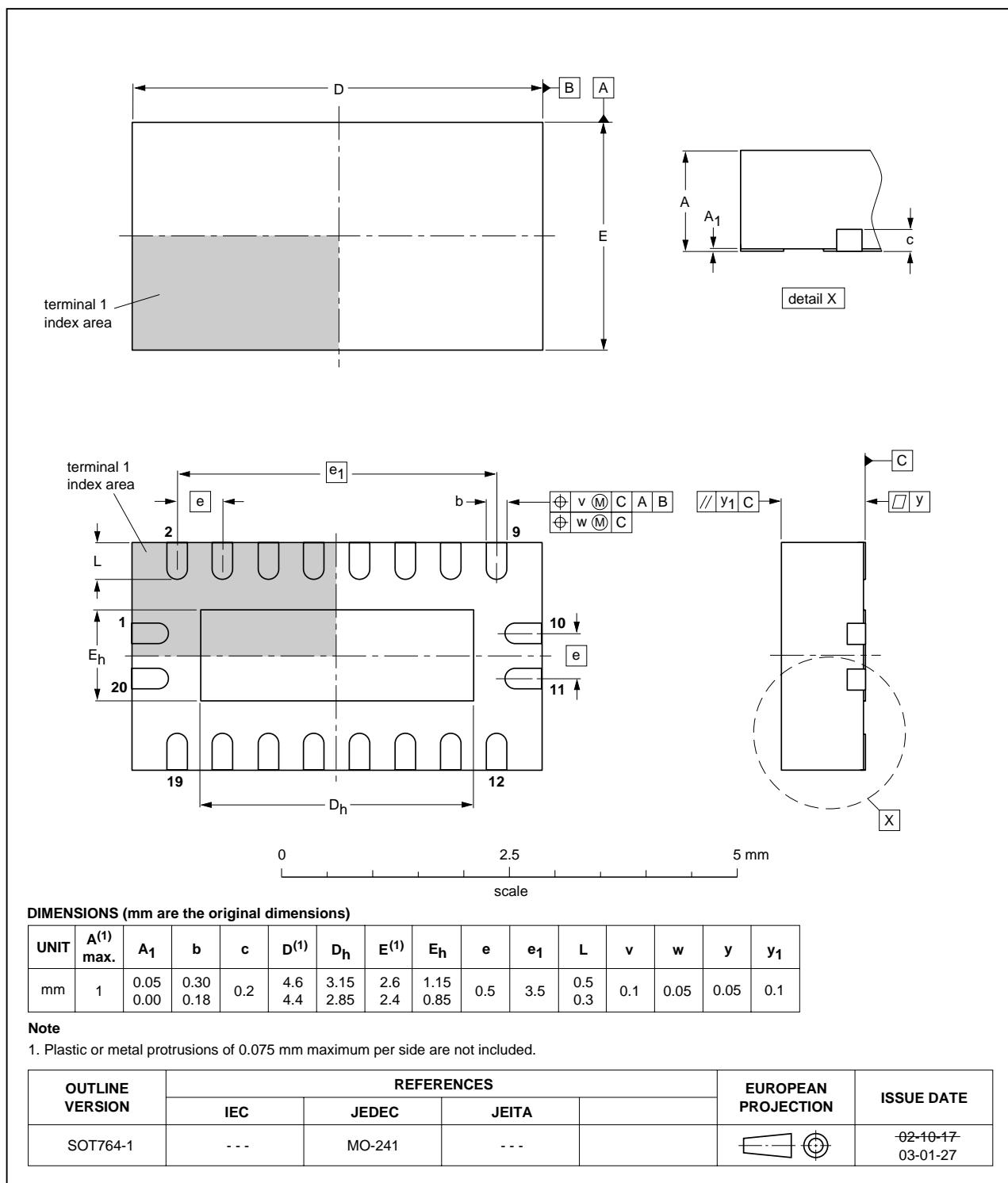


Fig 13. Package outline SOT764-1 (DHVQFN20)

## 13. Abbreviations

**Table 10. Abbreviations**

Acronym	Description
BiCMOS	Integrated Bipolar junction transistors and CMOS
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

## 14. Revision history

**Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT273_3	20080910	Product data sheet	-	74LVT273_2
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Title changed to 3.3 V octal D-type flip-flop</li> <li><a href="#">Section 3 “Ordering information”</a> and <a href="#">Section 12 “Package outline”</a> DHVQFN20 package added.</li> <li><a href="#">Table 4 “Limiting values”</a> <math>T_j</math> and <math>P_{tot}</math> values added.</li> </ul>			
74LVT273_2	19980219	Product specification	-	-

## 15. Legal information

## 16. Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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